

NCE0224K

Pb Free Product

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0224K uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

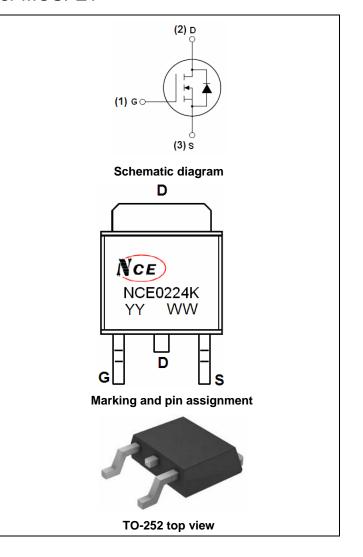
- V_{DS} =200V,I_D =24A $R_{DS(ON)} < 80 \text{m}\Omega$ @ $V_{GS} = 10 \text{V}$ (Typ:64m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0224K	NCE0224K	TO-252	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	24	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	17	Α
Pulsed Drain Current	I _{DM}	100	А
Maximum Power Dissipation	P _D	150	W
Single pulse avalanche energy (Note 5)	E _{AS}	250	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$

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NCE0224K

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1	°C/W	
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Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	•					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2.5	3.2	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =15A	-	64	80	mΩ
Forward Transconductance	g FS	V _{DS} =50V,I _D =15A	30	-	-	S
Dynamic Characteristics (Note4)	•					
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/		4200		PF
Output Capacitance	Coss	V _{DS} =25V,V _{GS} =0V,		163		PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz		75		PF
Switching Characteristics (Note 4)	•					
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	t _r	V _{DD} =100V,I _D =15A	-	18	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =10 V , R_{GEN} =2.5 Ω	-	22	-	nS
Turn-Off Fall Time	t _f		-	5	-	nS
Total Gate Charge	Qg	V 400V/1 45A		60		nC
Gate-Source Charge	Q_{gs}	V_{DS} =100V, I_{D} =15A, V_{GS} =10V		19		nC
Gate-Drain Charge	Q_{gd}	V _{GS} -10V		17		nC
Drain-Source Diode Characteristics	•					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =11A	-	-	1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	24	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 15A	-	90	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	300	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

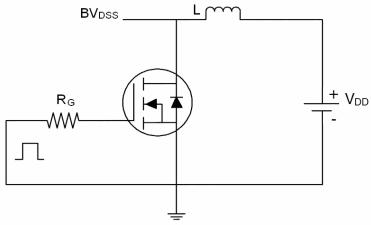
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=100V,V_G=10V,L=0.5mH,Rg=25 Ω



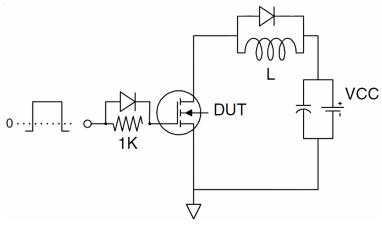
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Test Circuit

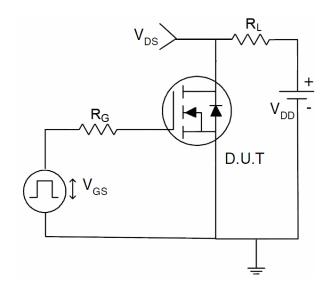
1) E_{AS} test Circuits



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

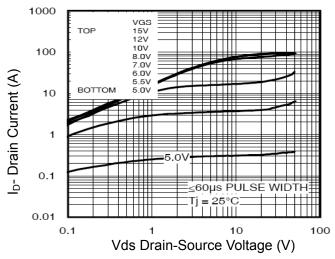


Figure 1 Output Characteristics

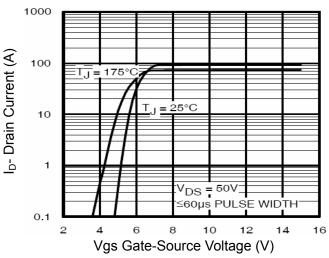


Figure 2 Transfer Characteristics

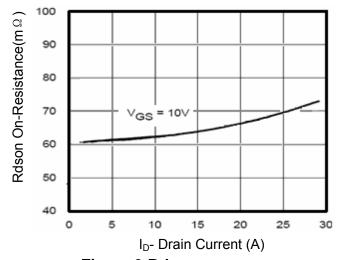


Figure 3 Rdson- Drain Current

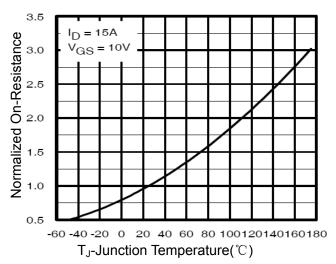


Figure 4 Rdson-JunctionTemperature

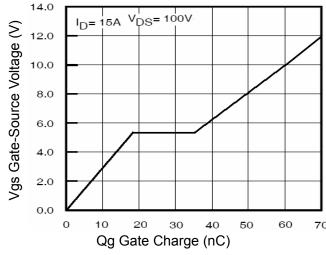


Figure 5 Gate Charge

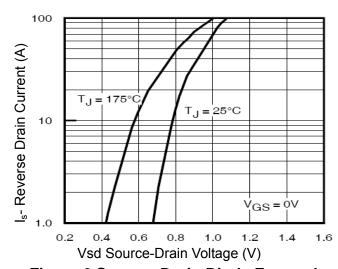


Figure 6 Source- Drain Diode Forward



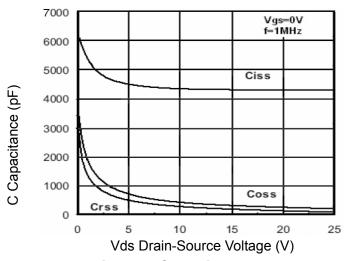


Figure 7 Capacitance vs Vds

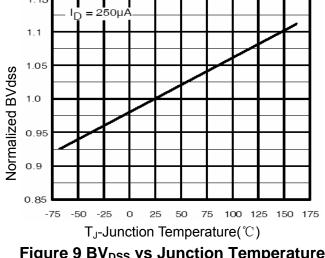


Figure 9 BV_{DSS} vs Junction Temperature

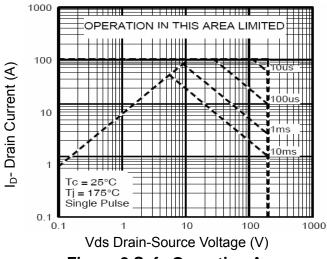
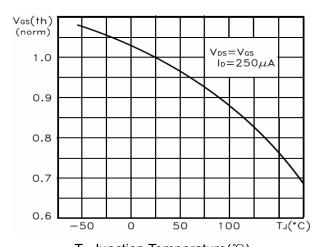


Figure 8 Safe Operation Area



 T_J -Junction Temperature($^{\circ}$ C)

Figure 10 V_{GS(th)} vs Junction Temperature

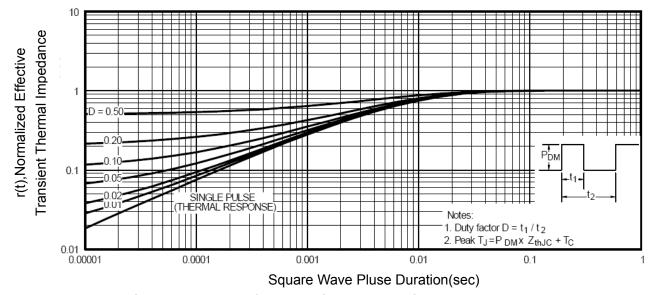


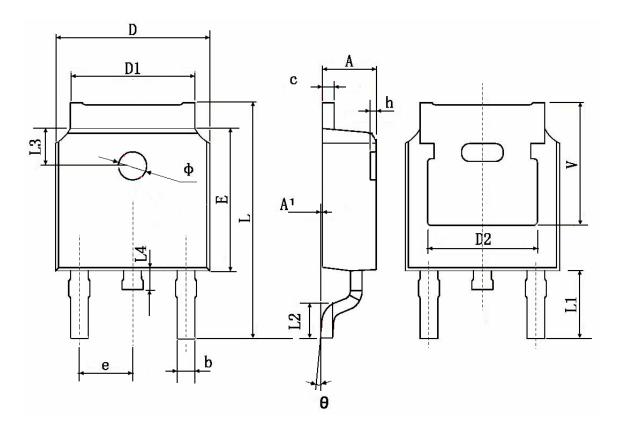
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483	0.483 TYP.		TYP.	
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	0.114 TYP.		YP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	1.600 TYP.		TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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